

Solve and Implement the main Equations of Photovoltaic Cell Parameters Using Visual Studio Program

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Abstract: In the present work, the main equations of Photovoltaic cell parameters are designed and implemented using visual Studio program. The important equations parameters of a solar cells is short-circuit current I_{sc} , open-voltage circuit V_{oc} , the voltage, the current at maximum power V_m and I_m respectively, incident power density, maximum power P_m , fill factor FF and the photovoltaic efficiency of the cell η .

Keywords: Important parameters, photovoltaic cell, visual studio, C sharp language

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1. Introduction

C Sharp language is an extension of the language C and C++ and ease of Visual Basic and JavaScript was released in June 2000, it is still fledgling. Were created by Microsoft by team Microsoft led Anders Hejlsberg an engineer distinct Microsoft was produced products and other languages, contains Borland Delphi and Borland Turbo C++ and focused engineer Elsie sharp to take the strengths that characterize the other languages with add enhancements to do this a better language. C sharp is strong and flexible like the rest of the languages we can create many different applications^[1]. Valsa sharp depends only on your imagination. Do not put this language restrictions on what you are doing have been used in projects with multiple forms as dynamic web sites and development tools and translation software and many others. The C language was created sharp programming language using objects. Many believe that there is no need for new programming languages, languages found Kjava and the C++, Delphi and visual basic enough to meet all needs^[2]. Although the CIA sharp derived from that C and C++

has been created from scratch without relying on those languages and included several new features making it easier and similar to Java in some similar characteristics^[3-4]. Solar cells are the procedure of converting intensity of light immediately to electric charge using photovoltaic effect. Many kinds of PV can be fabricated based on the materials used and the method of fabrication in order to obtain economic solar cells with high efficiencies such as; indium tin oxide (ITO), niobium doped titanium dioxide ($TiO_2:Nb$), zinc oxide (ZnO), nickel oxide (NiO), Bismuth trioxide (Bi_2O_3) and aluminum doped zinc oxide (AZO) which are used in rigid and flexible electronics^[5-9]. Many kinds of photovoltaic cell such as silicon, inorganic and organic solar cells^[10-14]. In addition several good materials can be utilized to enhanced the efficiency of solar cells because of their excellent optical properties such as zinc tungstate, sodium tungstate, sodium cadmium orthophosphate, copper doped zinc oxide^[15-19]. For other applications of solar cells in space based on Kepler equation; in addition using linear programming and fuzzy logic and set theory^[20-31].

In this paper, the main equations of solar cell physical parameters have been demonstrated and implemented using Visual Studio program. The advantages of using C sharp are simple, modern, a strong and elastic language, using the programming language objects.

2. Experimental Method

In this study, the method including Visual Studio C# program a design method to calculate PV physical parameters and conversion efficiency evolutionary algorithms were briefly described.

3. Results and Discussion

The design of the main equations to solve and implement the output of the solar cell parameters for any values of the input parameters using C sharp program; the major physical factors are utilized to describe the rendering of PV cell are the maximum power P_{max} , current density J_{sc} , V_{oc} , and FF .

4. The Open Circuit Voltage V_{oc} ^[32]

Eq. for V_{oc} is obtained by precision $I = 0$; this equation indicate the linearity behaviour of V_{oc} that decreases with temperature in (Kelven).

$$V_{oc} = \frac{KT}{q} \ln \frac{I_L}{I_o} \quad 1$$

where $T (K) = 273.15 + T^o (C)$

The V_{oc} can too be calculated based on a carrier concentration

$$V_{oc} = \frac{KT}{q} \ln \frac{(N_A + \Delta n) \times \Delta n}{n_i^2} \quad 2$$

where $\frac{KT}{q}$: thermal voltage, N_A : doping concentration, Δn : carrier concentration (excessing) and n_i : carrier concentration (intrinsic). The calculation of V_{oc} from the n_i .

Eqs. 1 and 2 is designed and implemented to calculate the value of V_{oc} shown in Figs. 7, 10.

5. Solar Cell Efficiency η ^[33]

PV quantum efficiency is calculated from a part of incident energy which is transmitted to electric current

$$\eta_1 = \frac{I_m \times V_m}{V_{oc} \times I_{sc}} \times 100\% \quad 3$$

$$\eta_2 = \frac{V_{oc} \times I_{sc} \times FF}{E \times A} \times 100\% \quad 4$$

$$\eta_3 = \frac{V_{oc} \times I_{sc} \times FF}{P_{in}} \times 100\% \quad 5$$

$$\eta_4 = \frac{P_m}{P_{in}} \times 100\% \quad 6$$

$$P_m = I_m \times V_m \quad 7$$

and

$$P_{in} = E \times A \quad 8$$

$$\eta = \frac{P_m}{P_{new}} \times 100\% \quad 9$$

$$\eta = \frac{I_m \times V_m}{P_{in}} \times 100\% \quad 10$$

where

η : PV efficiency, E : energy photon, A : area of the cell.

Eqs. 3, 4, 5, 6, 7, 8, 9, 10 are used to calculate the value of fill factor is illustrated in **Figure 3**, **Figure 5**-**Figure 9**.

6. Maximum Power

The equations below indicate the relation between the maximum power and the maximum current and voltage

$$P_m = I_m \times V_m, \quad 11$$

$$= J_m \times V_m \quad 12$$

$$= V_{oc} \times I_{sc} \times FF \quad 13$$

$$P_{new} = P_{old} \times A \quad 14$$

The Eqs. 11, 12, 13, 14 are utilize to calculate an efficiency of a PV cell and designed as shown in **Figure 4**- **Figure 8**.

7. Fill Factor FF

FF is described based on the ratio of maximum output power divided on V_{oc} multiplied by I_{sc} of the PV cell, so that

$$FF = \frac{P_m}{V_{oc} \times I_{sc}} \quad 15$$

$$= \frac{I_m \times V_m}{V_{oc} \times I_{sc}} \quad 16$$

when

$$\frac{d(IV)}{dV} = 0$$

$$V_{Mp} = V_{oc} - \frac{n \times K \times T}{q} - \ln \left(\frac{q \times V_{Mp}}{n \times K \times T} + 1 \right) \quad 17$$

where v_{oc} : normalized V_{oc} and the above equation needs Lambert functions to solve but a simpler approach is to use iteration to calculate V_{Mp} .

$$FF = \frac{v_{oc} - \ln(v_{oc} + 0.72)}{v_{oc} + 1} \quad 18$$

v_{oc} : normalized V_{oc}

$$v_{oc} = \frac{q}{nKT} \times V_{oc} \quad 19$$

The Eqs. 15, 16, 17, 18, 19 are utilize to calculate the efficiency of a PV shown in Figs. 6, 1, 11, 7, 2,

All the figures with the programs are listed below

```

private
void button1_Click(object sender,
EventArgs e)
{
    Voc
Convert.ToDouble(textBox1.Text);
n
Convert.ToDouble(textBox2.Text);
k
Convert.ToDouble(textBox3.Text);
t
Convert.ToDouble(textBox4.Text);
q
Convert.ToDouble(textBox5.Text);
Vm
Convert.ToDouble(textBox6.Text);

k1
Convert.ToDouble(textBox8.Text);
q1
Convert.ToDouble(textBox9.Text);

p1 = k * Math.Pow(10, k1);
p2 = q * Math.Pow(10, q1);

Vmp = Voc - ((n * p1 * t) / p2)
* Math.Log((Vm / ((n * p1 * t) / p2)) + 1);

textBox7.Text
Vmp.ToString();
}

private void button2_Click(object
sender, EventArgs e)
{
    k
Convert.ToDouble(textBox3.Text);
k1
Convert.ToDouble(textBox8.Text);
p1 = k * Math.Pow(10, k1);
textBox10.Text
= p1.ToString();
}

```

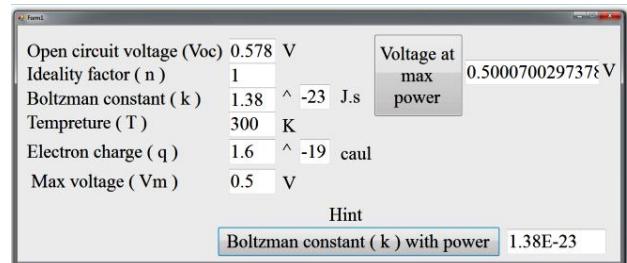


Figure 1. the value of the open-circuit voltage.

>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>

```

private void button1_Click(object
sender, EventArgs e)
{
    double q, n, k, t, Vold, Vnew,
k1, q1, p1, p2;

    q
Convert.ToDouble(textBox1.Text);
n
Convert.ToDouble(textBox2.Text);
k
Convert.ToDouble(textBox3.Text);
t
Convert.ToDouble(textBox4.Text);
Vold
Convert.ToDouble(textBox5.Text);

k1
Convert.ToDouble(textBox8.Text);
q1
Convert.ToDouble(textBox7.Text);

p1 = k * Math.Pow(10, k1);
p2 = q * Math.Pow(10, q1);

```

```

Vnew = (p2 / (n * p1 * t)) * Vold;
textBox6.Text
Vnew.ToString();
}

```

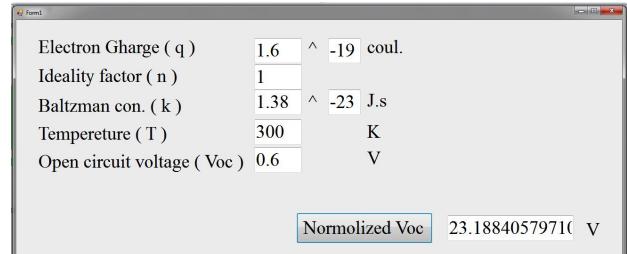


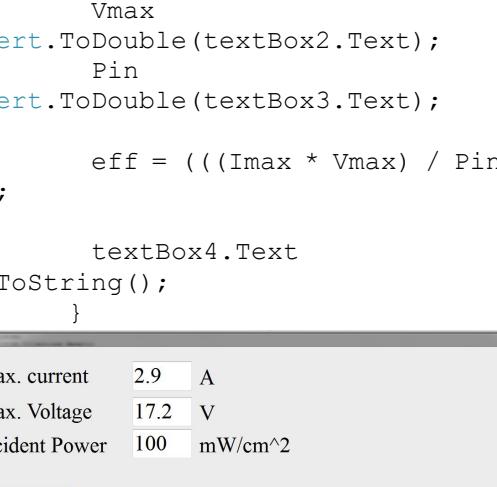
Figure 2. The value of open-circuit voltage.

>>>>>>>>>>>>>>>>>>>>>>>>>>>>

```

private void button1_Click(object
sender, EventArgs e)
{
    double Imax, Vmax, Pin, eff;
}

```

```
    Imax  
Convert.ToDouble(textBox1.Text);  
    Vmax  
Convert.ToDouble(textBox2.Text);  
    Pin  
Convert.ToDouble(textBox3.Text);  
  
    eff = (((Imax * Vmax) / Pin) *  
100);  
  
    textBox4.Text  
eff.ToString();  
}  
  


|                |       |                    |
|----------------|-------|--------------------|
| Max. current   | 2.9   | A                  |
| Max. Voltage   | 17.2  | V                  |
| Incident Power | 100   | mW/cm <sup>2</sup> |
| Efficiency     | 49.88 | %                  |


```

Figure 3. The value of efficiency.

```

    Voc
Convert.ToDouble(textBox6.Text);
    FF
Convert.ToDouble(textBox7.Text);

    textBox10.Text = (Isc * Voc * 
FF).ToString();
}

```

Max. cur. 2.9 A	Max. Vol. 17.2 V	max. o/p pow den 1	49.88	
Cur. dens. 3.52 A/m ²	Max. Vol2 1.2 V	max o/p pow den 2	4.224	
Sh. cur. 3.25 A	Op. cu. vol. 21.8 V	FF 0.704	max o/p pow den 3	49.8784

Figure 4. The value of maximum power density.

```

Voc = Convert.ToDouble(textBox3.Text);
Convert.ToDouble(textBox4.Text); FF =
Convert.ToDouble(textBox5.Text); E =
Convert.ToDouble(textBox6.Text); A =
Convert.ToDouble(textBox7.Text);

        textBox11.Text = (((FF * Isc * Voc) / (E * A)) * 100).ToString();
    }

    private void button3_Click(object sender, EventArgs e)
    {
        Isc = Convert.ToDouble(textBox3.Text);
        Voc = Convert.ToDouble(textBox4.Text);
        FF = Convert.ToDouble(textBox5.Text);
        Pin = Convert.ToDouble(textBox8.Text);

        textBox12.Text = (((FF * Isc * Voc) / (Pin)) * 100).ToString();
    }

    private void button4_Click(object sender, EventArgs e)
    {
        Pin = Convert.ToDouble(textBox8.Text);
        Pm = Convert.ToDouble(textBox9.Text);

        textBox13.Text = (((Pm) / (Pin)) * 100).ToString();
    }

    private void Form1_Load(object sender, EventArgs e)
    {

    }

    private void button5_Click(object sender, EventArgs e)
    {
        Im = Convert.ToDouble(textBox1.Text);
        Vm = Convert.ToDouble(textBox2.Text);
        Isc = Convert.ToDouble(textBox3.Text);

```

= Convert.ToDouble(textBox1.Text);
= Convert.ToDouble(textBox2.Text);
= Convert.ToDouble(textBox3.Text);

```

        Voc = Convert.ToDouble(textBox4.Text);
        FF = Convert.ToDouble(textBox5.Text);
        E = Convert.ToDouble(textBox6.Text);
        W = Convert.ToDouble(textBox7.Text);

        textBox9.Text = ((Im * Vm) / (Isc * Voc)).ToString();
    }

    private void button6_Click(object sender, EventArgs e)
    {
        Im = Convert.ToDouble(textBox1.Text);
        Vm = Convert.ToDouble(textBox2.Text);

        textBox9.Text = (Im * Vm).ToString();
    }

    private void button7_Click(object sender, EventArgs e)
    {
        E = Convert.ToDouble(textBox6.Text);
        A = Convert.ToDouble(textBox7.Text);

        textBox8.Text = (E / A).ToString();
    }
}


```

	Im	Vm	Isc	Voc	FF	Area	Pin	Pm	Eff.	Value	%
Eff.1	2.9	17.2	3.25	21.8	0.70402	0.46	217.3	49.88	Eff.1	70.4022	%
Eff.2									Eff.2	108.434	%
Eff.3									Eff.3	22.9448	%
Eff.4									Eff.4	22.9448	%

Figure 5. The value of the efficiency.

```

private void button1_Click(object sender, EventArgs e)
{
    double Voc, Isc, FF, Pmax;
    Voc = Convert.ToDouble(textBox1.Text);
    Isc = Convert.ToDouble(textBox2.Text);
    FF = Convert.ToDouble(textBox3.Text);
}

```

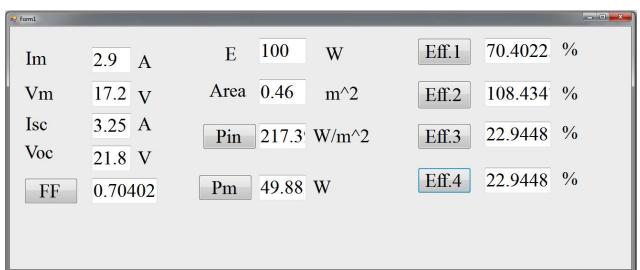
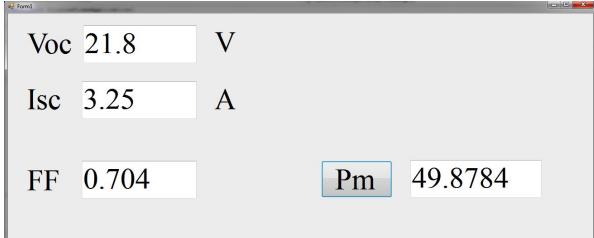


Figure 5. The value of the efficiency.

```

        Pmax = Voc * Isc * FF;
        textBox4.Text = Pmax.ToString();
    }

```

Figure 6. The value of maximum power density.

```
>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>
```

```

double T, k, t, q, IL, Io, Io1, p3, p1,
p2, ki, q1;

```

```

        private
void button2_Click(object sender,
EventArgs e)
{
    double k1;
    k = Convert.ToDouble(textBox2.Text);
    T = Convert.ToDouble(textBox1.Text);
    q = Convert.ToDouble(textBox4.Text);
    IL = Convert.ToDouble(textBox5.Text);
    Io = Convert.ToDouble(textBox6.Text);

    k1 = Convert.ToDouble(textBox9.Text);
    q1 = Convert.ToDouble(textBox11.Text);
    Io1 = Convert.ToDouble(textBox10.Text);

    p1 = k * Math.Pow(10, k1);
    p2 = q * Math.Pow(10, q1);
    p3 = Io * Math.Pow(10, Io1);
}

```

```

    textBox8.Text = (((p1 * T) /
p2) * Math.Log10((IL / p3))).ToString();
}

```

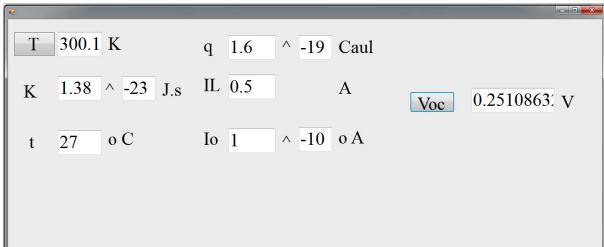
```

private void Form1_Load(object
sender, EventArgs e)
{
}

```

```

        private
void button3_Click(object sender,
EventArgs e)
{
    textBox1.Text = (273.15 +
Convert.ToDouble(textBox3.Text)).ToString();
}

```

Figure 7. The value of open-circuit voltage.

```
>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>>
```

```

double Voc, Isc, FF,
Pmax, Pold, A, Pnew, eff;

```

```

        private
void button1_Click(object sender,
EventArgs e)
{
    Voc = Convert.ToDouble(textBox1.Text);
    Isc = Convert.ToDouble(textBox2.Text);
    FF = Convert.ToDouble(textBox3.Text);

    Pmax = Voc * Isc * FF;

    textBox4.Text = Pmax.ToString();
    textBox5.Text = textBox4.Text;
}

        private
void button2_Click(object sender,
EventArgs e)
{
    Pold = Convert.ToDouble(textBox5.Text);
    A = Convert.ToDouble(textBox6.Text);

    Pnew = Pold * A;

    textBox7.Text = Pnew.ToString();
}

        private
void button3_Click(object sender,
EventArgs e)
{
}

```

```
    eff = (Pmax / Pnew) * 100;
    textBox8.Text      =
eff.ToString();
}
```

Voc	0.611	V	Pold	1.49695	W*m^2
Isc	3.5	A	Area	100	m^2
FF	0.7		Pnew	149.695	W
Pmax	1.49695	W	efficiency	1	%

Figure 8. The value of maximum power and efficiency.

Imax.	2.9	A
Vmax.	17.2	V
Pin	100	
Eff.	49.88	%

Figure 9. The value of the efficiency.

```
NA
Convert.ToDouble(textBox4.Text);
dn
Convert.ToDouble(textBox5.Text);
ni
Convert.ToDouble(textBox6.Text);

k1
Convert.ToDouble(textBox8.Text);
q1
Convert.ToDouble(textBox9.Text);
NA1
Convert.ToDouble(textBox10.Text);
dn1
Convert.ToDouble(textBox11.Text);
nil
Convert.ToDouble(textBox12.Text);
```

```

    p1 = k * Math.Pow(10, k1);
    p2 = q * Math.Pow(10, q1);
    p3 = NA * Math.Pow(10, NA1);
    p4 = dn * Math.Pow(10, dn1);
    p5 = ni * Math.Pow(10, ni1);

    Voc = ((p1 * t) / p2) *
Math.Log(((p3 + p4) * p4) / (p5 * p5));

    textBox7.Text =
Voc.ToString();
}

```

K	1.38	\wedge	-23	J.s	dn	1	\wedge	15	cm $^{-3}$
T	298		k	ni	8.6	\wedge	9	cm $^{-3}$	
q	1.6	\wedge	-19	caul					
NA	1.5	\wedge	16	cm $^{-3}$	Voc	0.6708374458	V		

Figure 10. The value of open-circuit voltage.

Figure 11. The value of fill factor.

>>>>>>>>>>>>>>>>>>>>>>>>>>>>>

8. Conclusion

The solar cell parameters is presented by Microsoft Visual Studio C # program is utilized to investigate the η of the solar cell. Elsie sharp came to eliminate the problems of Java and C++ languages, Faqamt cancel macro templates and multiple inheritance this caused confusion with the developers of C++ as well as the emergence of problems. In this research, the programs have been written in C sharp to design some of the equations for the calculation parameters basic task for solar cells, so that given any value for the input parameters produce direct value output of the parameters essential for any solar cell. An example of this if we want to calculate the efficiency of silicon solar cell, give input values is beyond capacity and falling evaluates efficiency value directly without the need to account through personal calculator and therefore; this method facilitates the process of calculating the parameters for any given input values.

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